

September 2015

# **KSC815 NPN Epitaxial Silicon Transistor**

## **Features**

- · Low Frequency Amplifier and High Frequency Oscillator
- Collector-Base Voltage: V<sub>CBO</sub> = 60 V
- · Complement to KSA539
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)
- Non Suffix "-C" means Side Collector (1. Emitter 2. Base 3. Collector)



## **Ordering Information**

| Part Number | Top Mark | Package  | Packing Method |  |
|-------------|----------|----------|----------------|--|
| KSC815YTA   | C815     | TO-92 3L | Ammo           |  |

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}\text{C}$  unless otherwise noted.

| Symbol                              | Parameter                 | Value      | Unit |
|-------------------------------------|---------------------------|------------|------|
| V <sub>CBO</sub>                    | Collector-Base Voltage    | 60         | V    |
| V <sub>CEO</sub>                    | Collector-Emitter Voltage | 45         | V    |
| V <sub>EBO</sub>                    | Emitter-Base Voltage      | 5          | V    |
| I <sub>C</sub>                      | Collector Current         | 200        | mA   |
| T <sub>J</sub> Junction Temperature |                           | 150        | °C   |
| T <sub>STG</sub>                    | Storage Temperature       | -55 to 150 | °C   |

## Thermal Characteristics(1)

Values are at  $T_A = 25$ °C unless otherwise noted.

| Symbol          | Parameter                               | Value | Unit |
|-----------------|---|-------|------|
| P <sub>C</sub>  | Collector Power Dissipation             | 400   | mW   |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | 310   | °C/W |

#### Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

## **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

| Symbol                | Parameter                            | Conditions   | Min. | Тур. | Max. | Unit |
|-----------------------|--------------------------------------|--|------|------|------|------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | $I_C = 100 \mu A, I_E = 0$                               | 65   |      |      | V    |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0               | 45   |      |      | V    |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | $I_E = 10 \mu A, I_C = 0$                                | 5    |      |      | V    |
| I <sub>CBO</sub>      | Collector Cut-Off Current            | $V_{CB} = 45 \text{ V}, I_{E} = 0$                       |      |      | 0.1  | μΑ   |
| I <sub>EBO</sub>      | Emitter Cut-Off Current              | $V_{EB} = 3 \text{ V}, I_{C} = 0$                        |      |      | 0.1  | μΑ   |
| h <sub>FE</sub>       | DC Current Gain                      | $V_{CE} = 1 \text{ V}, I_{C} = 50 \text{ mA}$            | 40   | \.   | 400  |      |
| V <sub>BE</sub> (on)  | Base-Emitter On Voltage              | $V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$           | 0.60 | 0.65 | 0.90 | V    |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$              |      | 0.15 | 0.40 | V    |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$              |      | 0.83 | 1.10 | V    |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | $V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$           | 100  | 200  | _    | MHz  |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0,<br>f = 1 MHz |      | 4    |      | pF   |

## h<sub>FE</sub> Classification

| Classification  | R       | 0        | Y         | G         |
|-----------------|---------|----------|-----------|-----------|
| h <sub>FF</sub> | 40 ~ 80 | 70 ~ 140 | 120 ~ 240 | 200 ~ 400 |

## **Typical Performance Characteristics**

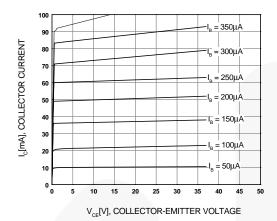


Figure 1. Static Characteristic

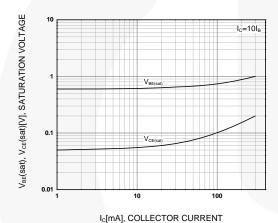


Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

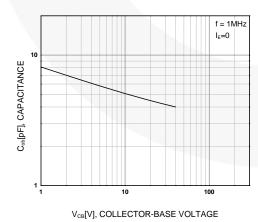


Figure 5. Collector Output Capacitance

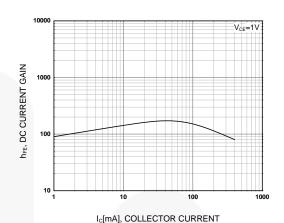


Figure 2. DC Current Gain

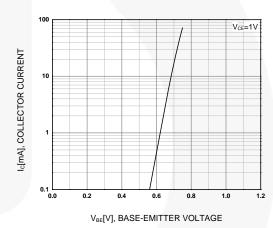


Figure 4. Base-Emitter On Voltage

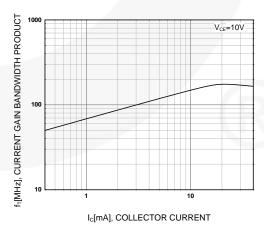
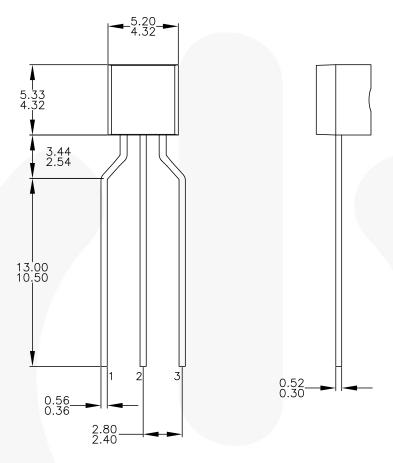
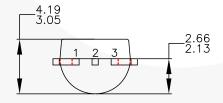


Figure 6. Current Gain Bandwidth Product

## **Physical Dimensions**





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZAO3FREV3. FAIRCHILD SEMICONDUCTOR.

Figure 7. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo Type





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